

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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2DB1119S

PNP SURFACE MOUNT TRANSISTOR

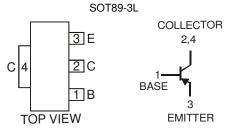
Features

- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)





Schematic and Pin Configuration

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V_{EBO}	-5	V
Peak Pulse Current	I _{CM}	-2	Α
Continuous Collector Current	Ic	-1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

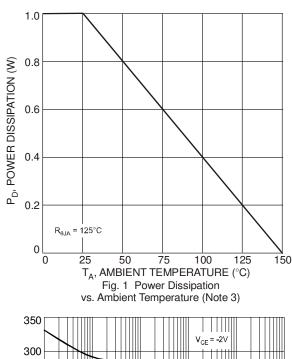
Electrical Characteristics @T_A = 25°C unless otherwise specified

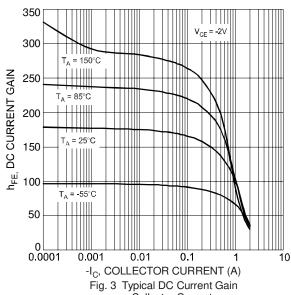
Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-25	_	_	V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-25	_	_	V	$I_C = -1 \text{ mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5	_	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}	_	_	-0.1	μΑ	$V_{CB} = -20V, I_{E} = 0$
Emitter Cut-Off Current	I _{EBO}	_	_	-0.1	μΑ	$V_{EB} = -4V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.15	-0.7	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		-0.85	-1.2	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
DC Current Gain	h _{FE}	140		280	_	$V_{CE} = -2V, I_{C} = -50mA$
DC Current Gain		40	_		_	$V_{CE} = -2V, I_{C} = -1A$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T		200		MHz	$V_{CE} = -10V, I_{C} = -50mA$ f = 100MHz
Output Capacitance	C _{ob}	_	12	_	pF	$V_{CB} = -10V, I_{E} = 0,$ f = 1MHz

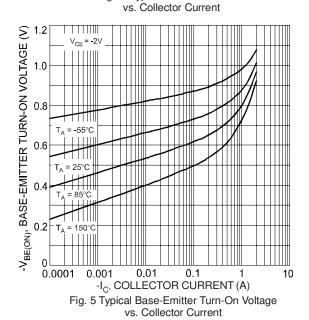
Notes: No purposefully added lead.

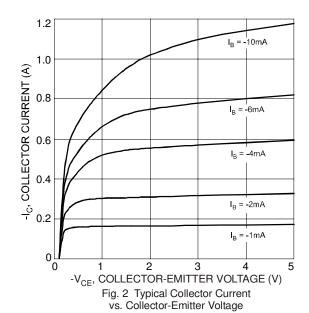
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.











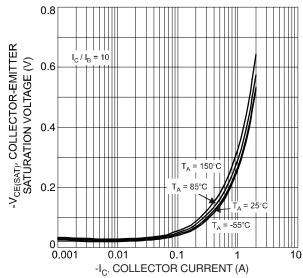
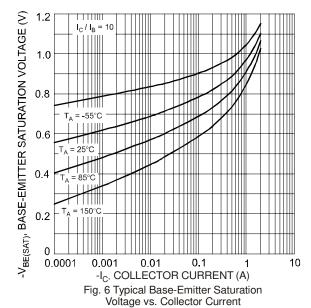
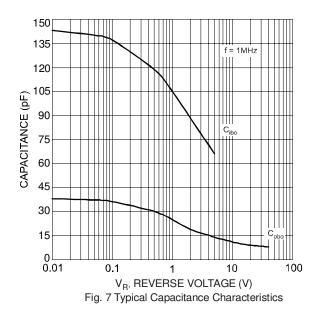


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current







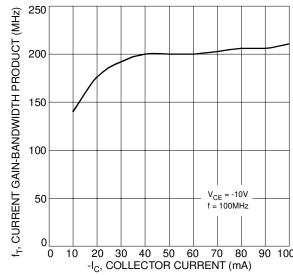


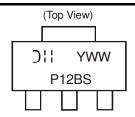
Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Ordering Information (Note 5)

Device	Packaging	Shipping
2DB1119S-13	SOT89-3L	2500/Tape & Reel

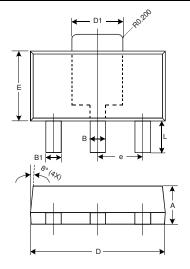
5. For packaging details, please see below or go to our website at http://www.diodes.com/ap02007.pdf.

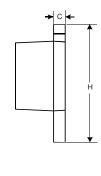
Marking Information



P12BS = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year ex: 7 = 2007WW = Week code 01 - 52

Package Outline Dimensions

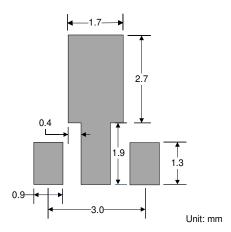




SOT89-3L					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.45	0.55	0.50		
B1	0.37	0.47	0.42		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.50	1.70	1.60		
Е	2.40	2.60	2.50		
е	_	_	1.50		
Н	3.95	4.25	4.10		
L	0.90	1.20	1.05		
All Dimensions in mm					



Suggested Pad Layout



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